

EAST - [thinnew2.wsp:1]

FileViewEditToolsWindowHelp

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Saved

S1: (119) "6545906"

S5: (2) "20020163058"

S4: (1) 10/261225

S3: (1) 11/240179

S2: (29) "6567246"

S6: (26) "6117747"

S7: (1) 11/155340

S8: (1722) plasma near reaction near chamber

S9: (12) RF near plasma near reaction near chamber

S10: (188) S8 same reactor

S11: (2) 10/715376

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DBsUS-PBPUB:USPAT:EPD:JPO:DERWENT:IBM_TDB

Default operator:OR

10/715376

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BRS formIS&R formImageTextHTML

	U		Document ID	Issue Date	Pages	Title	Current OR	Current XRef	Retrieval Cla	Invento	S	C	P	3	Image Doc. Displaye	P	T
1			US 20060104110	20060518	15	Spin-current switchable magnetic memory element and method of fabri	365/173			Sun; Jonatha					US 20060104110		
2			US 20050104101	20050519	14	Spin-current switched magnetic memory element suitable for circuit in	257/295	257/E27.005; 257/E43.004		Sun, Jonatha					US 20050104101		

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